

Frederic Grillot

List of Publications by Year in descending order

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251
papers

3,406
citations

136740

32
h-index

189595

50
g-index

254
all docs

254
docs citations

254
times ranked

1825
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | Free-Space Communication With Directly Modulated Mid-Infrared Quantum Cascade Devices. IEEE Journal of Selected Topics in Quantum Electronics, 2022, 28, 1-9. | 1.9 | 46 |
| 2 | Competition between Entrainment Phenomenon and Chaos in a Quantum-Cascade Laser under Strong Optical Reinjection. Photonics, 2022, 9, 29. | 0.9 | 2 |
| 3 | Mid-infrared free-space cryptosystem. Nonlinear Theory and Its Applications IEICE, 2022, 13, 44-52. | 0.4 | 2 |
| 4 | Mid-infrared hyperchaos of interband cascade lasers. Light: Science and Applications, 2022, 11, 7. | 7.7 | 22 |
| 5 | 10 Gbit s ⁻¹ Free Space Data Transmission at 9.4 μm Wavelength With Unipolar Quantum Optoelectronics (Laser Photonics Rev. 16(2)/2022). Laser and Photonics Reviews, 2022, 16, . | 4.4 | 1 |
| 6 | A review of recent results of mid-infrared quantum cascade photonic devices operating under external optical control. JPhys Photonics, 2022, 4, 022001. | 2.2 | 3 |
| 7 | Modeling of Amplitude Squeezing in a Pump-Noise-Suppressed Interband Cascade Laser. IEEE Photonics Journal, 2022, 14, 1-8. | 1.0 | 5 |
| 8 | Spectral dispersion of the linewidth enhancement factor and four wave mixing conversion efficiency of an InAs/GaAs multimode quantum dot laser. Applied Physics Letters, 2022, 120, . | 1.5 | 6 |
| 9 | Effects of external optical feedback in InAs/InP quantum dot frequency comb lasers on silicon. , 2022, , . | | 0 |
| 10 | High-definition video broadcasting with a room-temperature quantum cascade laser emitting in the long-wave infrared domain. , 2022, , . | | 1 |
| 11 | Chaos-based mid-infrared communications. , 2022, , . | | 0 |
| 12 | Multimode Physics in the Mode Locking of Semiconductor Quantum Dot Lasers. Applied Sciences (Switzerland), 2022, 12, 3504. | 1.3 | 6 |
| 13 | Reflection sensitivity of InAs/GaAs epitaxial quantum dot lasers under direct modulation. Electronics Letters, 2022, 58, 363-365. | 0.5 | 1 |
| 14 | 10 Gbit s ⁻¹ Free Space Data Transmission at 9.4 μm Wavelength With Unipolar Quantum Optoelectronics. Laser and Photonics Reviews, 2022, 16, . | 4.4 | 35 |
| 15 | Analysis of the Spontaneous Emission Limited Linewidth of an Integrated III-V/SiN Laser (Laser) Tj ETQq1 1 0.784314 rgBT /Overloc | 4.4 | 1 |
| 16 | Dynamic and nonlinear properties of epitaxial quantum-dot lasers on silicon operating under long- and short-cavity feedback conditions for photonic integrated circuits. Physical Review A, 2021, 103, . | 1.0 | 15 |
| 17 | Dynamics of epitaxial quantum dot laser on silicon subject to chip-scale back-reflection for isolator-free photonics integrated circuits. , 2021, , . | | 0 |
| 18 | Private communication with quantum cascade laser photonic chaos. Nature Communications, 2021, 12, 3327. | 5.8 | 55 |

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| 19 | Effect of Shockley-Read-Hall recombination on the static and dynamical characteristics of epitaxial quantum-dot lasers on silicon. <i>Physical Review A</i> , 2021, 103, . | 1.0 | 6 |
| 20 | Uncovering recent progress in nanostructured light-emitters for information and communication technologies. <i>Light: Science and Applications</i> , 2021, 10, 156. | 7.7 | 25 |
| 21 | Modeling of a quantum dot gain chip in an external cavity laser configuration. <i>Laser Physics</i> , 2021, 31, 085002. | 0.6 | 3 |
| 22 | Dynamic performance and reflection sensitivity of quantum dot distributed feedback lasers with large optical mismatch. <i>Photonics Research</i> , 2021, 9, 1550. | 3.4 | 11 |
| 23 | Stimulating polarization switching dynamics in mid-infrared quantum cascade lasers. <i>Journal of the Optical Society of America B: Optical Physics</i> , 2021, 38, B35. | 0.9 | 2 |
| 24 | Chaos synchronization in mid-infrared quantum cascade lasers for private free-space communication. , 2021, , . | | 0 |
| 25 | Perspectives on Advances in Quantum Dot Lasers and Integration with Si Photonic Integrated Circuits. <i>ACS Photonics</i> , 2021, 8, 2555-2566. | 3.2 | 67 |
| 26 | Recent progress in quantum dot distributed feedback lasers with large wavelength detuning for uncooled and isolation-free applications. , 2021, , . | | 0 |
| 27 | Relative intensity noise and intrinsic properties of RF mounted interband cascade laser. <i>Applied Physics Letters</i> , 2021, 119, . | 1.5 | 10 |
| 28 | The above-threshold linewidth enhancement factor of silicon-based quantum dot lasers. , 2021, , . | | 0 |
| 29 | Epitaxial quantum dot lasers on silicon with high thermal stability and strong resistance to optical feedback. <i>APL Photonics</i> , 2020, 5, . | 3.0 | 32 |
| 30 | Dynamic properties of two-state lasing quantum dot laser for external optical feedback resistant applications. , 2020, , . | | 1 |
| 31 | Optical Noise of Dual-State Lasing Quantum Dot Lasers. <i>IEEE Journal of Quantum Electronics</i> , 2020, 56, 1-7. | 1.0 | 17 |
| 32 | Temperature dependent linewidth rebroadening in quantum dot semiconductor lasers. <i>Journal Physics D: Applied Physics</i> , 2020, 53, 235106. | 1.3 | 2 |
| 33 | High coherence collapse of a hybrid III-V/Si semiconductor laser with a large quality factor. <i>JPhys Photonics</i> , 2020, 2, 025005. | 2.2 | 6 |
| 34 | Spectral linewidth reduction of quantum cascade lasers by strong optical feedback. <i>Journal of Applied Physics</i> , 2020, 127, . | 1.1 | 9 |
| 35 | 1.3- μm passively mode-locked quantum dot lasers epitaxially grown on silicon: gain properties and optical feedback stabilization. <i>JPhys Photonics</i> , 2020, 2, 045006. | 2.2 | 11 |
| 36 | Quantum dot lasers based photonics integrated circuits. , 2020, , . | | 3 |

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| 37 | Extreme events in quantum cascade lasers. <i>Advanced Photonics</i> , 2020, 2, . | 6.2 | 17 |
| 38 | Towards private optical communications with mid-infrared chaotic light. , 2020, , . | | 5 |
| 39 | Effect of p-doping on the intensity noise of epitaxial quantum dot lasers on silicon. <i>Optics Letters</i> , 2020, 45, 4887. | 1.7 | 21 |
| 40 | Physics and applications of quantum dot lasers for silicon photonics. <i>Nanophotonics</i> , 2020, 9, 1271-1286. | 2.9 | 38 |
| 41 | Systematic investigation of the influencing parameters of an external cavity laser with a quantum dot gain chip. , 2020, , . | | 0 |
| 42 | All-optical modulation at mid-infrared wavelength with QCLs. , 2020, , . | | 0 |
| 43 | Frequency-domain modeling of semiconductor mode lock lasers. , 2020, , . | | 0 |
| 44 | An Indirect Determination of the Polarization Anisotropy in a Quantum Cascade Laser Under Strong Cross-Polarization Feedback. , 2020, , . | | 0 |
| 45 | Tunable All-Optical Modulation and Building Blocks for Optical Neurons at Mid-Infrared Wavelength. , 2020, , . | | 0 |
| 46 | Excitability in Mid-Infrared Quantum Cascade Lasers: from Communication Jamming to Neuromorphic Photonics. , 2020, , . | | 0 |
| 47 | Uncovering reflection insensitive semiconductor lasers for silicon photonic integration. , 2020, , . | | 0 |
| 48 | Frequency comb dynamics of a 13 μ m hybrid-silicon quantum dot semiconductor laser with optical injection: erratum. <i>Optics Letters</i> , 2020, 45, 856. | 1.7 | 0 |
| 49 | Epitaxial integration of high-performance quantum-dot lasers on silicon. , 2020, , . | | 3 |
| 50 | Peculiarities and predictions of rogue waves in mid-infrared quantum cascade lasers under conventional optical feedback. , 2020, , . | | 0 |
| 51 | P-doping effect on external optical feedback dynamics in 1.3-microns InAs/GaAs quantum dot laser epitaxially grown on silicon. , 2020, , . | | 2 |
| 52 | Influence of the polarization anisotropy on the linewidth enhancement factor and reflection sensitivity of 1.55- μ m InP-based InAs quantum dash lasers. <i>Applied Physics Letters</i> , 2019, 115, . | 1.5 | 11 |
| 53 | Enhanced Chaotic Performance with Optically Injected Quantum Cascade Lasers. , 2019, , . | | 0 |
| 54 | 1.3- μ m Reflection Insensitive InAs/GaAs Quantum Dot Lasers Directly Grown on Silicon. <i>IEEE Photonics Technology Letters</i> , 2019, 31, 345-348. | 1.3 | 83 |

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| 55 | Intensity Noise and Pulse Oscillations of an InAs/GaAs Quantum Dot Laser on Germanium. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, 1-10. | 1.9 | 3 |
| 56 | Chaotic optical power dropouts driven by low frequency bias forcing in a mid-infrared quantum cascade laser. Scientific Reports, 2019, 9, 4451. | 1.6 | 14 |
| 57 | Investigation of Chaotic and Spiking Dynamics in Mid-Infrared Quantum Cascade Lasers Operating Continuous-Waves and Under Current Modulation. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, 1-11. | 1.9 | 18 |
| 58 | 10 Gbps Error-Free Transmission of a High Coherent Si/III-V Hybrid Distributed Feedback Laser under Strong Optical Feedback. , 2019, , . | | 1 |
| 59 | Thermally insensitive determination of the chirp parameter of InAs/GaAs quantum dot lasers epitaxially grown onto silicon. , 2019, , . | | 1 |
| 60 | Extensive study of the linewidth enhancement factor of a distributed feedback quantum cascade laser at ultra-low temperature. , 2019, , . | | 6 |
| 61 | Study of short and mid-wavelength infrared telecom links performance for different climatic conditions. , 2019, , . | | 4 |
| 62 | Frequency comb dynamics of a 13 μ m hybrid-silicon quantum dot semiconductor laser with optical injection. Optics Letters, 2019, 44, 5755. | 1.7 | 18 |
| 63 | Dynamic and nonlinear properties of epitaxial quantum dot lasers on silicon for isolator-free integration. Photonics Research, 2019, 7, 1222. | 3.4 | 27 |
| 64 | High frequency dynamics in quantum cascade lasers : a roadmap to free-space communications in the mid-infrared. , 2019, , . | | 0 |
| 65 | Controlling the Likelihood of Extreme Pulses in a Quantum Cascade Laser with Optical Feedback and Bias Perturbation. , 2019, , . | | 0 |
| 66 | Square Wave Emission in a Mid-infrared Quantum Cascade Oscillator Under Rotated Polarization. , 2019, , . | | 1 |
| 67 | Linewidth broadening factor and optical feedback sensitivity of silicon based quantum dot lasers. , 2019, , . | | 0 |
| 68 | Narrow spectral linewidth in InAs/InP quantum dot distributed feedback lasers. Applied Physics Letters, 2018, 112, . | 1.5 | 44 |
| 69 | Low Linewidth Enhancement Factor and High Optical Feedback Resistance of p-Doped Silicon Based Quantum Dot Lasers. , 2018, , . | | 1 |
| 70 | Dynamic and Noise Properties of High-Q Hybrid Laser. , 2018, , . | | 3 |
| 71 | Carrier-Noise-Enhanced Relative Intensity Noise of Quantum Dot Lasers. IEEE Journal of Quantum Electronics, 2018, 54, 1-7. | 1.0 | 26 |
| 72 | Utilizing the Complex Dynamics of InAs/GaAs Quantum Dot lasers for Ultrafast Devices. , 2018, , . | | 0 |

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| 73 | Design, Fabrication and Characterization of Hybrid III-V/SOI Phase-Shift Free DFB Laser with Tapered Silicon Waveguide. , 2018, , . | | 1 |
| 74 | Low-frequency fluctuations of a mid-infrared quantum cascade laser operating at cryogenic temperatures. Laser Physics Letters, 2018, 15, 116201. | 0.6 | 16 |
| 75 | Introduction to the Issue on Physics and Applications of Laser Dynamics (IS-PALD 2017). Optics Express, 2018, 26, 21375. | 1.7 | 0 |
| 76 | Comparison of optical feedback dynamics of InAs/GaAs quantum-dot lasers emitting solely on ground or excited states. Optics Letters, 2018, 43, 210. | 1.7 | 18 |
| 77 | Semiconductor quantum dot lasers epitaxially grown on silicon with low linewidth enhancement factor. Applied Physics Letters, 2018, 112, . | 1.5 | 63 |
| 78 | Multimode optical feedback dynamics in InAs/GaAs quantum dot lasers emitting exclusively on ground or excited states: transition from short- to long-delay regimes. Optics Express, 2018, 26, 1743. | 1.7 | 23 |
| 79 | Rate equation modeling of the frequency noise and the intrinsic spectral linewidth in quantum cascade lasers. Optics Express, 2018, 26, 2325. | 1.7 | 22 |
| 80 | Frequency noise suppression of optical injection-locked quantum cascade lasers. Optics Express, 2018, 26, 15167. | 1.7 | 19 |
| 81 | Experimental investigation of broad area quantum cascade lasers under external feedback. Optics Express, 2018, 26, 17927. | 1.7 | 3 |
| 82 | Relative intensity noise properties of quantum dot lasers. , 2018, , . | | 3 |
| 83 | Analysis of the optical feedback dynamics in InAs/GaAs quantum dot lasers directly grown on silicon. Journal of the Optical Society of America B: Optical Physics, 2018, 35, 2780. | 0.9 | 56 |
| 84 | 10-Gb/s Floor-Free Transmission of a Hybrid III-V on Silicon Distributed Feedback Laser with Optical Feedback. , 2018, , . | | 0 |
| 85 | Influence of the upper nonlasing state on the route to chaos of InAs/GaAs quantum dot lasers. , 2018, , . | | 0 |
| 86 | The Effect of Temperature on the Dynamical States of a Time Delayed Mid-infrared Quantum Cascade Oscillator. , 2018, , . | | 0 |
| 87 | Temperature dependence of a mid-infrared quantum cascade laser with external optical feedback. , 2018, , . | | 0 |
| 88 | Ultrafast and nonlinear dynamics of InAs/GaAs semiconductor quantum dot lasers. , 2018, , . | | 0 |
| 89 | Temperature dependence of spectral linewidth of InAs/InP quantum dot distributed feedback lasers. , 2018, , . | | 0 |
| 90 | Large-signal capabilities of an optically injection-locked semiconductor laser using gain lever. , 2018, , . | | 0 |

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| 91 | Talbot coupling of an array of quantum cascade lasers. , 2018, , . | | 2 |
| 92 | Recent advances in InAs/GaAs quantum dot lasers with short optical feedback. , 2018, , . | | 0 |
| 93 | Beam steering in quantum cascade lasers with optical feedback. , 2017, , . | | 2 |
| 94 | Wideband chaos in hybrid III-V/silicon distributed feedback semiconductor lasers under optical feedback. , 2017, , . | | 1 |
| 95 | Linewidth Rebroadening in Quantum Dot Semiconductor Lasers. IEEE Journal of Selected Topics in Quantum Electronics, 2017, 23, 1-10. | 1.9 | 11 |
| 96 | Beam shaping in high-power broad-area quantum cascade lasers using optical feedback. Scientific Reports, 2017, 7, 44284. | 1.6 | 13 |
| 97 | Passive Chaos Bandwidth Enhancement Under Dual-Optical Feedback with Hybrid III-V/Si DFB Laser. IEEE Journal of Selected Topics in Quantum Electronics, 2017, 23, 1-9. | 1.9 | 18 |
| 98 | Long delay optical feedback sensitivity of hybrid III-V/SOI directly modulated DFB lasers. , 2017, , . | | 0 |
| 99 | Effects of gain nonlinearities in an optically injected gain lever semiconductor laser. Photonics Research, 2017, 5, 315. | 3.4 | 2 |
| 100 | Controllable rare events in optically-injected semiconductor lasers. , 2017, , . | | 0 |
| 101 | Complex delay dynamics of high power quantum cascade oscillators. , 2017, , . | | 1 |
| 102 | Contribution of off-resonant states to the phase noise of quantum dot lasers. Optics Express, 2016, 24, 29872. | 1.7 | 26 |
| 103 | Low Phase Noise Quantum Dot Lasers for Coherent Communication Networks. , 2016, , . | | 0 |
| 104 | Chaotic light at mid-infrared wavelength. Light: Science and Applications, 2016, 5, e16088-e16088. | 7.7 | 65 |
| 105 | Multimode optical feedback dynamics of InAs/GaAs quantum-dot lasers emitting on different lasing states. AIP Advances, 2016, 6, 125114. | 0.6 | 19 |
| 106 | Measurements of the linewidth enhancement factor of mid-infrared quantum cascade lasers by different optical feedback techniques. AIP Advances, 2016, 6, . | 0.6 | 38 |
| 107 | Efficiency of four-wave mixing in injection-locked InAs/GaAs quantum-dot lasers. AIP Advances, 2016, 6, 125105. | 0.6 | 5 |
| 108 | Estimating optical feedback from a chalcogenide fiber in mid-infrared quantum cascade lasers. AIP Advances, 2016, 6, 105201. | 0.6 | 2 |

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| 109 | Thermally insensitive determination of the linewidth broadening factor in nanostructured semiconductor lasers using optical injection locking. Scientific Reports, 2016, 6, 27825. | 1.6 | 27 |
| 110 | InAs/GaAs excited state quantum-dot transmitters operating under long-delayed optical feedback. , 2016, , . | | 0 |
| 111 | Dynamics of Hybrid III-V Silicon Semiconductor Lasers for Integrated Photonics. IEEE Journal of Selected Topics in Quantum Electronics, 2016, 22, 43-49. | 1.9 | 14 |
| 112 | Optical nonlinearities in InAs/GaAs injection-locked quantum dot light-based emitters. Proceedings of SPIE, 2016, , . | 0.8 | 0 |
| 113 | Linewidth broadening factor and gain compression in quantum cascade lasers. Proceedings of SPIE, 2016, , . | 0.8 | 2 |
| 114 | Deterministic temporal chaos from a mid-infrared external cavity quantum cascade lasers. , 2016, , . | | 1 |
| 115 | Optically injected InAs/GaAs quantum dot laser for tunable photonic microwave generation. Optics Letters, 2016, 41, 1153. | 1.7 | 45 |
| 116 | Dynamics of optically-injected semiconductor nanolasers. Proceedings of SPIE, 2016, , . | 0.8 | 0 |
| 117 | Gain compression effect on the modulation dynamics of an optically injection-locked semiconductor laser using gain lever. , 2016, , . | | 1 |
| 118 | From Basic Physical Properties of InAs/InP Quantum Dots to State-of-the-Art Lasers for 1.55 μm Optical Communications. Advances in Materials Science and Engineering, 2016, , 95-125. | 0.4 | 4 |
| 119 | Dynamics of Excited-State InAs/GaAs Fabry-Perot Quantum-Dot Lasers under Optical Feedback. , 2016, , . | | 1 |
| 120 | Experimental investigation of the above-threshold linewidth broadening factor of a mid-infrared quantum cascade laser. , 2015, , . | | 0 |
| 121 | Highly efficient non-degenerate four-wave mixing under dual-mode injection in InP/InAs quantum-dash and quantum-dot lasers at 1.55 μm . Applied Physics Letters, 2015, 107, . | 1.5 | 10 |
| 122 | Time Resolved Chirp Measurement Based on a Polarization-Maintaining Fiber. IEEE Photonics Technology Letters, 2015, 27, 1557-1560. | 1.3 | 1 |
| 123 | Nonlinear dynamics of quantum cascade lasers with optical feedback. Proceedings of SPIE, 2015, , . | 0.8 | 3 |
| 124 | Nonlinear conversion efficiency of InAs/InP nanostructured Fabry-Perot lasers. Proceedings of SPIE, 2015, , . | 0.8 | 0 |
| 125 | Corrections to "Enhancement of the Modulation Dynamics of an Optically Injection-Locked Semiconductor Laser Using Gain Lever". IEEE Journal of Selected Topics in Quantum Electronics, 2015, 21, 792-792. | 1.9 | 1 |
| 126 | Non-linear and dynamic properties of MOVPE-grown InAs/InP quantum-dot and quantum-dash Fabry-Perot lasers. , 2015, , . | | 0 |

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| 127 | Highly efficient wavelength conversion in InAs/GaAs quantum dot lasers. , 2015, , . | | 0 |
| 128 | Dispersion uncompensated IM/DD transmissions of 12GHz-wide multi-band OFDM over 100km with a D-EML. , 2015, , . | | 1 |
| 129 | Optical feedback sensitivity of hybrid III-V silicon lasers. , 2015, , . | | 0 |
| 130 | Enhancement of the Modulation Dynamics of an Optically Injection-Locked Semiconductor Laser Using Gain Lever. IEEE Journal of Selected Topics in Quantum Electronics, 2015, 21, 575-582. | 1.9 | 1 |
| 131 | Periodic and aperiodic pulse generation using optically injected DFB laser. Electronics Letters, 2015, 51, 280-282. | 0.5 | 9 |
| 132 | Non-degenerate four-wave mixing in an optically injection-locked InAs/InP quantum dot Fabry-Perot laser. Applied Physics Letters, 2015, 106, . | 1.5 | 18 |
| 133 | Analysis of dual-mode lasing characteristics in a 1310-nm optically injected quantum dot distributed feedback laser. , 2015, , . | | 0 |
| 134 | Modulation-Frequency Dependence of the Phase-Amplitude Coupling in Quantum Dot Lasers. , 2015, , . | | 0 |
| 135 | Influence of inhomogeneous broadening on the dynamics of quantum dot lasers. , 2015, , . | | 1 |
| 136 | Frequency-dependent linewidth enhancement factor of optical injection-locked quantum dot/dash lasers. Optics Express, 2015, 23, 21761. | 1.7 | 7 |
| 137 | A Novel Method for Extracting the Linewidth Broadening Factor of Semiconductor Lasers. , 2015, , . | | 0 |
| 138 | Amplitude Modulation and Frequency Chirp of an Injection-Locked Quantum Dash Semiconductor Laser. , 2014, , . | | 0 |
| 139 | Nondegenerate four-wave mixing in a dual mode injection locked quantum dot laser. Proceedings of SPIE, 2014, , . | 0.8 | 0 |
| 140 | Impact of Absorber Bias Voltage on the Optical Feedback Sensitivity of a Passively Mode-Locked Quantum Dot Laser Operating at Elevated Temperature. , 2014, , . | | 0 |
| 141 | Phase-amplitude coupling of optically-injected nanostructured semiconductor lasers. , 2014, , . | | 0 |
| 142 | Linewidth enhancement factor in semiconductor lasers subject to various external optical feedback conditions. Optics Express, 2014, 22, 5651. | 1.7 | 15 |
| 143 | Self-referenced technique for monitoring and analysing the non-linear dynamics of semiconductor lasers. Optics Express, 2014, 22, 16528. | 1.7 | 0 |
| 144 | Strong optical injection and the differential gain in a quantum dash laser. Optics Express, 2014, 22, 7222. | 1.7 | 18 |

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| 145 | Introduction to the issue on Physics and Applications of Laser Dynamics (IS-PALD 2013). Optics Express, 2014, 22, 7362. | 1.7 | 1 |
| 146 | Phase-amplitude coupling characteristics in directly modulated quantum dot lasers. Applied Physics Letters, 2014, 105, 221114. | 1.5 | 18 |
| 147 | Regimes of external optical feedback in 5.6- μm distributed feedback mid-infrared quantum cascade lasers. Applied Physics Letters, 2014, 105, . | 1.5 | 33 |
| 148 | Tuning the external optical feedback-sensitivity of a passively mode-locked quantum dot laser. Applied Physics Letters, 2014, 105, 041112. | 1.5 | 3 |
| 149 | Impact of the gain model on the stability assessment in semiconductor DFB lasers. , 2014, , . | | 1 |
| 150 | Predicting modes of operation in quantum dot mode-locked lasers using a delay differential equation model. , 2014, , . | | 0 |
| 151 | Rate equation analysis of frequency chirp in optically injection-locked quantum cascade lasers. , 2014, , . | | 1 |
| 152 | Analysis of frequency chirp of self-injected nanostructure semiconductor lasers. IET Optoelectronics, 2014, 8, 51-57. | 1.8 | 1 |
| 153 | Corrections to "Enhanced Dynamic Performance of Quantum Dot Semiconductor Lasers Operating on the Excited State" [Sep 14 723-731]. IEEE Journal of Quantum Electronics, 2014, 50, 1072-1072. | 1.0 | 1 |
| 154 | Nondegenerate Four-Wave Mixing in a Dual-Mode Injection-Locked InAs/InP(100) Nanostructure Laser. IEEE Photonics Journal, 2014, 6, 1-8. | 1.0 | 9 |
| 155 | Enhanced Dynamic Performance of Quantum Dot Semiconductor Lasers Operating on the Excited State. IEEE Journal of Quantum Electronics, 2014, 50, 1-9. | 1.0 | 38 |
| 156 | Near-threshold relaxation dynamics of a quantum dot laser. Proceedings of SPIE, 2014, , . | 0.8 | 1 |
| 157 | High Performance Excited-State Nanostructure Lasers' Modulation Response, Frequency Chirp and Linewidth Enhancement Factor. , 2014, , . | | 0 |
| 158 | Control of dynamical instability in semiconductor quantum nanostructures diode lasers: Role of phase-amplitude coupling. European Physical Journal: Special Topics, 2013, 222, 813-820. | 1.2 | 15 |
| 159 | Systematic investigation of the temperature behavior of InAs/InP quantum nanostructure passively mode-locked lasers. Proceedings of SPIE, 2013, , . | 0.8 | 1 |
| 160 | Photonics based on carbon nanotubes. Nanoscale Research Letters, 2013, 8, 300. | 3.1 | 2 |
| 161 | Pulse Characterization of Passively Mode-Locked Quantum-Dot Lasers Using a Delay Differential Equation Model Seeded With Measured Parameters. IEEE Journal of Selected Topics in Quantum Electronics, 2013, 19, 1100311-1100311. | 1.9 | 10 |
| 162 | Modulation Properties of Self-Injected Quantum-Dot Semiconductor Diode Lasers. IEEE Journal of Selected Topics in Quantum Electronics, 2013, 19, 1900812-1900812. | 1.9 | 33 |

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| 163 | Intensity modulation response of injection-locked quantum cascade lasers. , 2013, , . | | 2 |
| 164 | Rate equation analysis of injection-locked quantum cascade lasers. Journal of Applied Physics, 2013, 113, 063104. | 1.1 | 38 |
| 165 | Bandwidth and dynamic range of a pulsed local oscillator coherent optical receiver: application to the linear optical sampling. Proceedings of SPIE, 2013, , . | 0.8 | 1 |
| 166 | Modulation properties of optically injection-locked quantum cascade lasers. Optics Letters, 2013, 38, 1975. | 1.7 | 26 |
| 167 | Impacts of carrier capture and relaxation rates on the modulation response of injection-locked quantum dot lasers. , 2013, , . | | 2 |
| 168 | Nonlinear dynamics and modulation properties of optically injected quantum cascade lasers. , 2013, , . | | 3 |
| 169 | Differential gain enhancement in a quantum dash laser using strong optical injection. Proceedings of SPIE, 2013, , . | 0.8 | 2 |
| 170 | Modeling and characterization of pulse shape and pulse train dynamics in two-section passively mode-locked quantum dot lasers. Proceedings of SPIE, 2013, , . | 0.8 | 1 |
| 171 | Self-injected semiconductor distributed feedback lasers for frequency chirp stabilization. Optics Express, 2012, 20, 26062. | 1.7 | 10 |
| 172 | GaAs-Based Quantum Dot Lasers. Semiconductors and Semimetals, 2012, 86, 371-417. | 0.4 | 31 |
| 173 | Delay differential equation-based modeling of passively mode-locked quantum dot lasers using measured gain and loss spectra. Proceedings of SPIE, 2012, , . | 0.8 | 2 |
| 174 | Frequency chirp stabilization in semiconductor distributed feedback lasers with external control. , 2012, , . | | 1 |
| 175 | Carrier escape from ground state and non-zero resonance frequency at low bias powers for semiconductor quantum-dot lasers. , 2012, , . | | 1 |
| 176 | Impacts of Wetting Layer and Excited State on the Modulation Response of Quantum-Dot Lasers. IEEE Journal of Quantum Electronics, 2012, 48, 1144-1150. | 1.0 | 58 |
| 177 | 20 GHz to 83 GHz single section InAs/InP quantum dot mode-locked lasers grown on (001) misoriented substrate. , 2012, , . | | 1 |
| 178 | Influence of facet phases on adiabatic chirp behavior of index-coupled distributed-feedback lasers. , 2012, , . | | 0 |
| 179 | Modelling the gain compression effects on semiconductor quantum-dot laser through a new modulation transfer function. , 2012, , . | | 2 |
| 180 | Dual-mode quantum dot laser operating in the excited state. , 2011, , . | | 0 |

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| 181 | Influence of the linewidth enhancement factor on the modulation response of a nanostructure-based semiconductor laser operating under external optical feedback. , 2011, , . | | 3 |
| 182 | RF linewidth of a monolithic quantum dot mode-locked laser under resonant feedback. IET Optoelectronics, 2011, 5, 105-109. | 1.8 | 5 |
| 183 | Measuring the Chirp and the Linewidth Enhancement Factor of Optoelectronic Devices with a Mach-Zehnder Interferometer. IEEE Photonics Journal, 2011, 3, 476-488. | 1.0 | 63 |
| 184 | Microwave Characterization and Stabilization of Timing Jitter in a Quantum-Dot Passively Mode-Locked Laser via External Optical Feedback. IEEE Journal of Selected Topics in Quantum Electronics, 2011, 17, 1311-1317. | 1.9 | 58 |
| 185 | PERFORMANCE OF A QUANTUM DOT PASSIVELY MODE-LOCKED LASER UNDER OPTICAL FEEDBACK AND TEMPERATURE CONTROL. International Journal of High Speed Electronics and Systems, 2011, 20, 679-685. | 0.3 | 1 |
| 186 | Enhanced Properties in Single-Walled Carbon Nanotubes Based Saturable Absorber for All Optical Signal Regeneration. Japanese Journal of Applied Physics, 2011, 50, 040206. | 0.8 | 2 |
| 187 | Direct characterization of carrier relaxation in a passively mode-locked quantum dot laser. , 2011, , . | | 0 |
| 188 | Simultaneous low linewidth enhancement factor and high bandwidth quantum-dash injection-locked laser. , 2011, , . | | 0 |
| 189 | A dual-mode quantum dot laser operating in the excited state. Applied Physics Letters, 2011, 99, 231110. | 1.5 | 21 |
| 190 | Enhanced Properties in Single-Walled Carbon Nanotubes Based Saturable Absorber for All Optical Signal Regeneration. Japanese Journal of Applied Physics, 2011, 50, 040206. | 0.8 | 1 |
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